## NSN 5961-01-420-8905

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-420-8905 **Inclosure Material:** Metal **Overall Length:** 0.270 inches **Overall Height:** 0.200 inches **Overall Width:** 0.270 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 drain to source voltage and 40.0 gate to source voltage and 40.0 gate non-trigger voltage, instantaneous **Current Rating Per Characteristic:** 50.00 milliamperes drain current **Power Rating Per Characteristic:** 1.2 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Mtd to mounting pad **Test Data Document:** 96214-804238 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**